

Floating Catalyst Chemical Vapor Deposition for Boron Nitride Nanotube Synthesis

Mioko Kawakami kawakami.mioko.48c@st.kyoto-u.ac.jp

Institute of Advance Energy, Kyoto University



THE JIANG UNIVERSITY

1. Introduction

Carbon Nanotube & Boron Nitride Nanotube

Carbon Nanotube (CNT)

Boron Nitride Nanotube (BNNT)

2. Experimental method

Floating Catalyst CVD (FCCVD)



- CNTs exhibit distinctive properties derived from their nanostructures. \rightarrow attracting significant attention for various applications^[5-8]
- BNNTs share the same structure as CNTs, with B and N replacing C.
 → <u>electrically insulating</u>, <u>optically transparent</u>, higher <u>chemical stabili-</u> ty than CNTs, while maintaining compareble <u>mechenical strength</u>

By combining with CNTs, BNNTs contributes as an enhancing and multifunctional nanotube material composite, surpassing the capabilities of carbon nanomaterials alone.

Boron Nitride Nanotube Synthesis

- Arc discharge^[9, 10] and laser ablation^[11, 12] have achieved high-quality BNNT synthesis. \triangle require high temp. (~3000°C), limiting scalabirity.
- Floating catalyst chemical vapor deposition (FCCVD) is promissing method for scalable BNNT synthesis^[13, 14].

 \triangle toxic borazine was mainly used as the BN source.

This work A parametric study aiming to synthesize BNNTs by FCCVD using <u>non-toxic ammonia borane</u> as a BN source



Growth conditions

BN source	Ammonia borane, heated to ~130°C to sumlime				
Catalyst	AuCl₃ (10mg),				
	placed in a holder with adjustable position				
BN flow rate	1.0-8.0 sccm	Pressure	5 kPa, 70 kPa		
Ar+H ₂ flow rate	200 sccm	H ₂ concentration	3%, 10%		
Growth temp.	1100°C	Growth time	1 hour		

3. Result & Discussion



High pressure (70 kPa)

- At a BN flow rate of 1 sccm, one-dimensional nanostructures were obtained.
- As the BN flow rate increased, the morphology changed
 → mainly because the growth rate was too fast.

Low pressure (5 kPa)

- At a BN flow rate of 1 sccm, many particles were observed on the grid.
- Increasing the BN flow rate resulted in larger deposits.

I.0 sccm, 5 kPa



- These particles, unlike those synthesized at high pressure, disappeared immediately upon electron irradiation
- → indicating that they were gold chloride, not pure gold.

→ Under low pressure, the flow was too fast for complate reduction of AuCl₃, thus possibly not allowing 1D structure growth.

TEM obsarvation

H₂ 3% (at a BN flow rate of l sccm, under 70 kPa)



H2 10% (at a BN flow rate of Isccm, under 70 kPa)



Amorphous phase nanofibres rather than crystalline nanotubes were obtained, under both H2 concentrations.

Effect of H₂ concentration (BN 1 sccm, 70 kPa)



• Increasing H₂ concentration results in shorter nanostructures. \rightarrow suggesting H₂ acted as an etchant for boron nitride.

- → To date, amorphous BN nanofibre synthesis has not been reported. It is possible that <u>a new material has been successfully synthesized</u> (elemental analysis by EELS will be performed soon).
- → These could be utilized as <u>ID nanoscale thremal insulators</u>, given that the phonons responsible for heat transfer are absent in amor phous materials.
- Metal nanoparticles are concentrated at rhe root of the nanofibres
 - \rightarrow indicating that metal catalysts activated the growth of nanofibres.

Summary Synthesis at a BN flow rate of Isccm under 70 kPa resulted in successful formation of ID nanostructures.

• TEM observation revealed these are amorphous nanofibres.

References [1] Y. Chen *et al. Appl. Phys. Lett.*, **84**, 2430 (2004) [2] M. B. Jalubinek *et al. J. Mater. Res.*, **37**, 4403 (2022) [3] R. Arenal *et al. Nanotechnology*, **22**, 265704 (2011) [4] N. G. Chopra and A. Zetti, *Sol. St. Commun.*, **105**, 297 (1998) [5] T. Nishihara *et al. Nat. Commun.*, **9**, 3144 (2018) [6] T. Nishihara *et al.* Nanophotonics, 11, 1011 (2022) [7] R. S. Jones *et al. Nanoscale Adv.*, **2**, 4996 (2020) [8] T. A. Abdullah *et al. Mater. Res. Express*, **10**, 122005 (2023) [9] A. Loiseau *et al. Phys. Rev. Lett.*, **76**, 4737 (1996) [10] A. Loiseau *et al. Carbon*, **36**, 743 (1998) [11] D. Golberg *et al. Chem. Phys. Lett.*, **279**, 191 (1997) [12] M. Xie *et al. J. Phys. Chem. C*, **114**, 16236 (2010) [13] S. Chatterjee *et al. Chem. Mater.*, **24**, 2872 (2012) [14] M. J. Kim *et al. Nano Lett.*, **8**, 3298 (2008)

